

We focus on power.

Revision 0.90

2014-06-16

page 1 of 4

BROAD AREA LASER

GaAs Semiconductor Laser Diode Single Emitter Structure









General Product Information

Product	Application
653 nm Broad Area Laser	Sensing
mounted on C-Mount	Medical



Absolute Maximum Ratings

	Symbol	Unit	min	typ	max
Storage Temperature	T_S	°C	-40		85
Operating Temperature at Case	T_{C}	°C	-20		30
Forward Current	I _F	Α			2.7
Reverse Voltage	V_R	V			2
Output Power	P_{opt}	W			1.2

non condensing non condensing Stress in excess of one of the Absolute Maximum Ratings can cause permanent damage to the device.

Recommended Operational Conditions

	Symbol	Unit	min	typ	max
Operating Temperature at Case	T _C	°C	10		25
Forward Current	I _F	А			2.5
Output Power	P_{opt}	W			1.0

Measurement Conditions / Comments
non condensing

Characteristics at T_{LD} = 25 °C at Begin Of Life

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm	648	653	658
Spectral Width (FWHM)	Δλ	nm		2	
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.3	
Output Power @ I _F = 2.5 A	P_{opt}	W	1.0		
Slope Efficiency	η_{d}	W/A		0.7	
Threshold Current	I _{th}	А		0.75	0.85
Operating Current @ $P_{opt} = 1.0 W$	I _{op}	А			2.5
Operating Voltage @ $P_{opt} = 1.0 W$	V_{op}	V		2.2	

Measurement Conditions / Comments
see images on page 4
total output measured with integrating sphere





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Revision 0.90





2014-06-16



page 2 of 4

Characteristics at T _{amb}	25 °C at E	3egin C	Of Life		cont'd	
Parameter	Symbol	Unit	min	typ	max	Measurement Conditions / Comments
Stripe Width	W_s	μm		100		
Cavity Length	L	μm		1500		
Divergence parallel (FWHM)	$\Theta_{ }$	0		8		Beam divergence parallel to junction plane
Divergence perpendicular (FWHM)	Θ_{\perp}	0		30		Beam divergence perpendicular to junction plane
Spectral Mode (longitudinal)				Multi Mode		
Polarization				TE		Polarization parallel to junction plane

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Revision 0.90





2014-06-16



page 3 of 4

Pack			ne

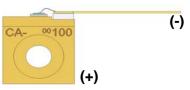
Parameter	Symbol	Unit	min	typ	max
Height of Emission Plane	h _{EP}	mm	7.05	7.20	7.35
C-Mount Thickness	d	mm		2.18	

Measurement Conditions / Comments	

Package Pinout

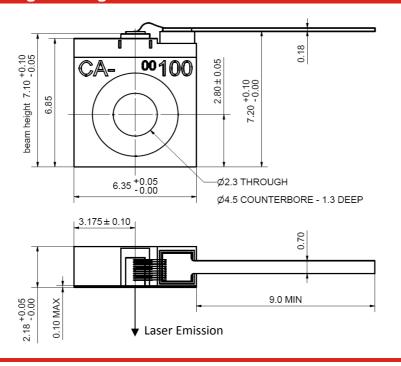
Cathode (-)	Mounting Wire
Anode (+)	Housing





heat spreader

Package Drawings







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Revision 0.90

2014-06-16

page 4 of 4

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Typical Measurement Results

Spectrum

Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The BAL diode type is known to be sensitive against thermal stress. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode. The chip should be protected against moisture. A water vapor content below 5000 ppm is recommended for applications with high reliability requirements

The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.





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